

# isc Silicon PNP Darlington Power Transistor

2SB1255

#### **DESCRIPTION**

- · High DC Current Gain-
  - : h<sub>FE</sub>= 5000(Min)@I<sub>C</sub>= -6A
- · Low-Collector Saturation Voltage-
- :  $V_{CE(sat)}$ = -2.5V(Max.)@ $I_{C}$ = -7A
- Complement to Type 2SD1895
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

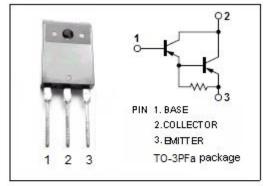


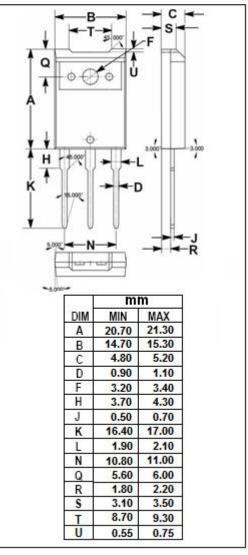
### **APPLICATIONS**

Designed for power amplifier applications

## ABSOLUTE MAXIMUM RATINGS(Ta=25℃)

SYMBOL	PARAMETER	VALUE	UNIT	
V <sub>СВО</sub>	Collector-Base Voltage	-160	V	
V <sub>CEO</sub>	Collector-Emitter Voltage	-140	V	
V <sub>EBO</sub>	Emitter-Base Voltage -5		V	
Ic	Collector Current-Continuous -8		А	
Ісм	Collector Current-Peak	-12 A		
P <sub>C</sub>	Collector Power Dissipation @ T <sub>C</sub> =25°C	100	W	
	Collector Power Dissipation @ T <sub>a</sub> =25 °C	3		
TJ	Junction Temperature	150	150 °C	
T <sub>stg</sub>	Storage Temperature Range	-55~150	-150 °C	







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#### **ELECTRICAL CHARACTERISTICS**

T<sub>C</sub>=25℃ unless otherwise specified

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SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
V <sub>(BR)CEO</sub>	Collector-Emitter Breakdown Voltage	I <sub>C</sub> = -30mA; I <sub>B</sub> = 0	-140			V
V <sub>CE(sat)</sub>	Collector-Emitter Saturation Voltage	I <sub>C</sub> = -7A; I <sub>B</sub> = -7mA			-2.5	V
V <sub>BE(sat)</sub>	Base-Emitter Saturation Voltage	I <sub>C</sub> = -7A; I <sub>B</sub> = -7mA			-3.0	V
I <sub>CBO</sub>	Collector Cutoff Current	V <sub>CB</sub> = -160V; I <sub>E</sub> = 0			-100	μА
Iceo	Collector Cutoff Current	V <sub>CE</sub> = -140V; I <sub>B</sub> = 0			-100	μА
I <sub>EBO</sub>	Emitter Cutoff Current	V <sub>EB</sub> = -5V; I <sub>C</sub> = 0			-100	μА
h <sub>FE-1</sub>	DC Current Gain	I <sub>C</sub> = -1A; V <sub>CE</sub> = -5V	2000			
h <sub>FE-2</sub>	DC Current Gain	I <sub>C</sub> = -7A; V <sub>CE</sub> = -5V	5000		30000	

### h<sub>FE-2</sub> Classifications

Q	Р			
5000-15000	8000-30000			

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